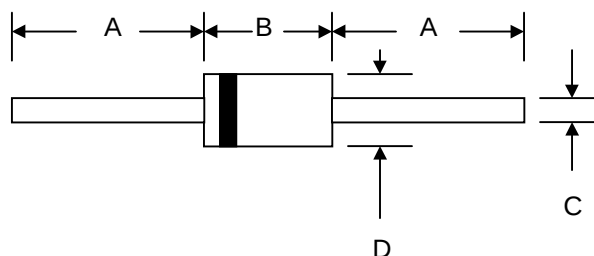


1.0A GLASS PASSIVATED FAST RECOVERY DIODE

Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability



Mechanical Data

- Case: DO-41, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.34 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- **Lead Free: For RoHS / Lead Free Version, Add "-LF" Suffix to Part Number, See Page 4**

DO-41		
Dim	Min	Max
A	25.4	—
B	4.06	5.21
C	0.71	0.864
D	2.00	2.72
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

Characteristic	Symbol	1N4933G	1N4934G	1N4935G	1N4936G	1N4937G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	200	400	600	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	V
Average Rectified Output Current (Note 1) @T _A = 75°C	I _O	1.0					A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	30					A
Forward Voltage @I _F = 1.0A	V _{FM}	1.2					V
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	I _{RM}	5.0 100					μA
Reverse Recovery Time (Note 2)	t _{rr}	200					nS
Typical Junction Capacitance (Note 3)	C _j	15					pF
Operating Temperature Range	T _j	-65 to +150					°C
Storage Temperature Range	T _{STG}	-65 to +150					°C

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case
 2. Measured with I_F = 0.5A, I_R = 1.0A, I_{RR} = 0.25A. See figure 5.
 3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

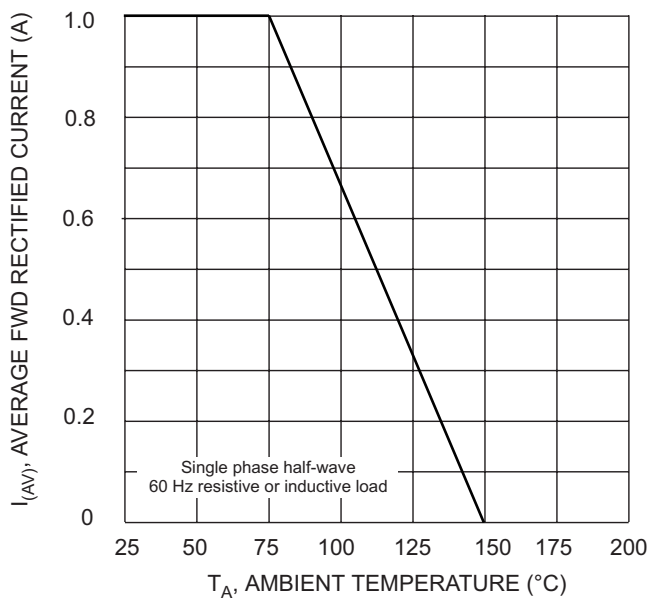


Fig. 1 Forward Derating Curve

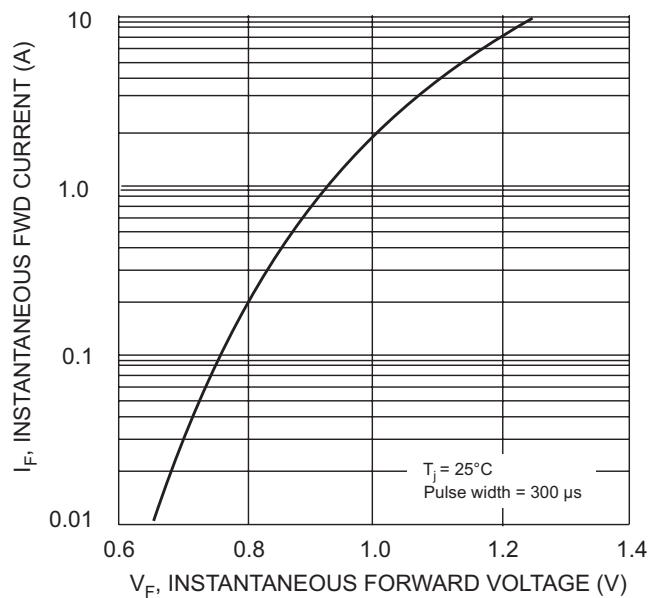


Fig. 2 Typical Forward Characteristics

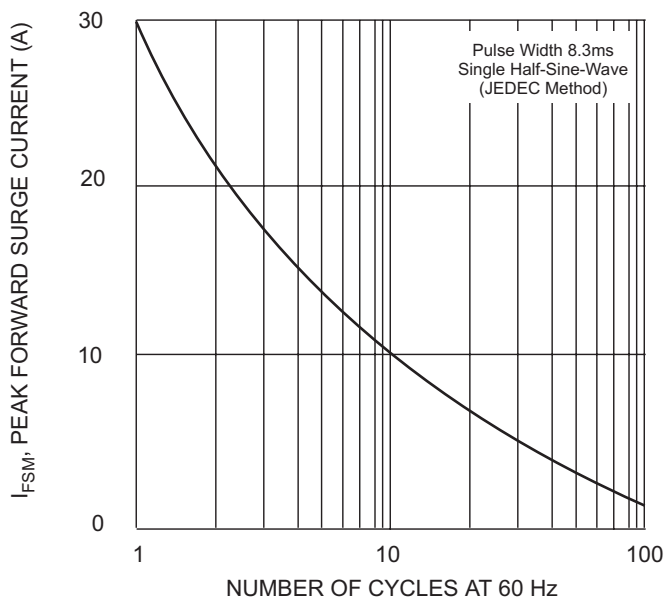


Fig. 3 Peak Forward Surge Current

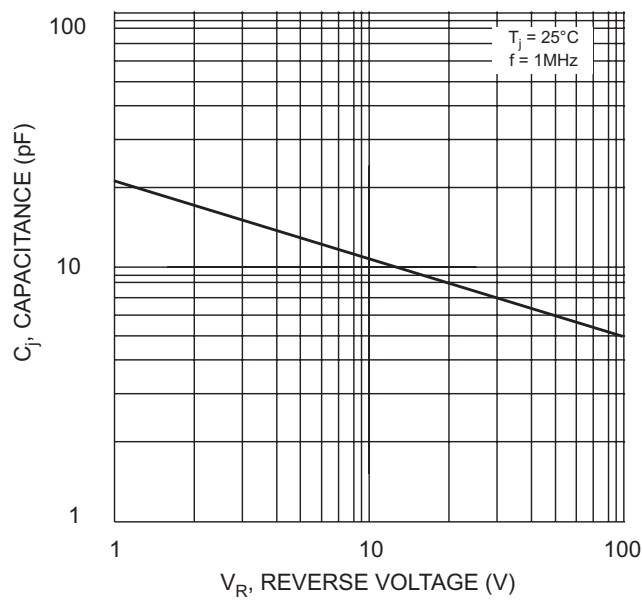
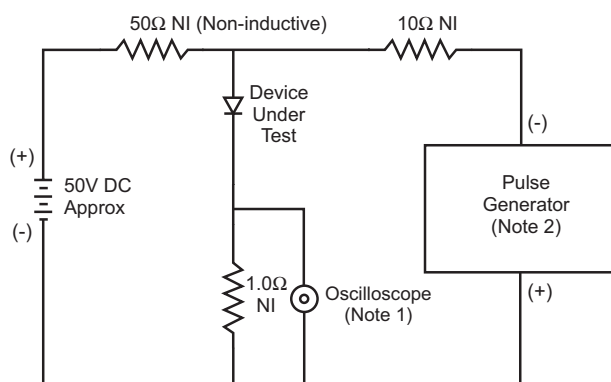


Fig. 4 Typical Junction Capacitance

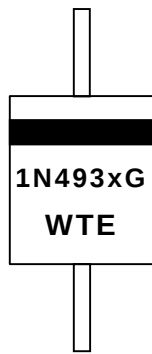


- Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
 2. Rise Time = 10ns max. Input Impedance = 50Ω.

Set time base for 5/10ns/cm

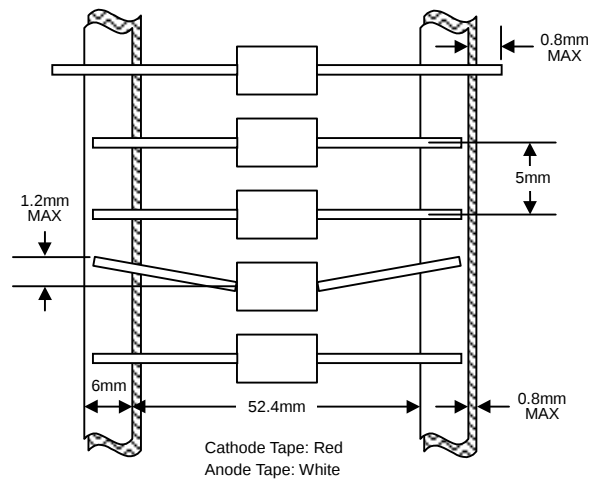
Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

MARKING INFORMATION



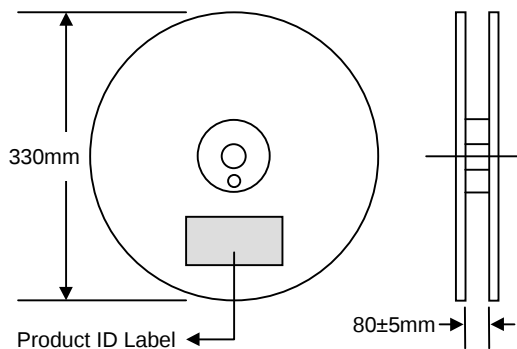
Cathode = Polarity Band
 1N493xG = Device Number
 x = 3, 4, 5, 6 or 7
 WTE = Manufacturer's Logo

TAPING SPECIFICATIONS

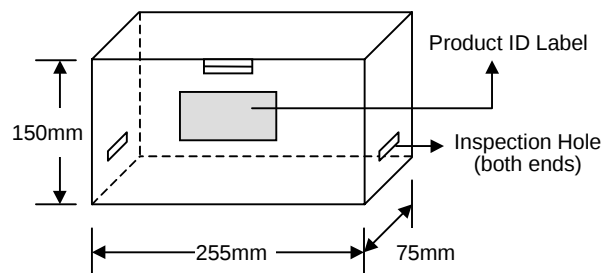


PACKAGING INFORMATION

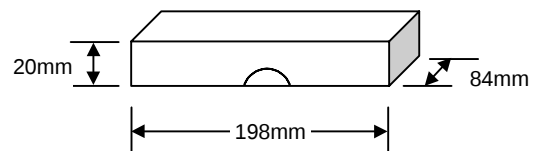
TAPE & REEL



TAPE & BOX



BULK



Packaging	Reel Diameter / Box Size (mm)	Quantity (PCS)	Carton Size (mm)	Quantity (PCS)	Approx. Gross Weight (KG)
TAPE & REEL	330	5,000	370 x 370 x 420	25,000	13.0
TAPE & BOX	255 x 75 x 150	5,000	400 x 273 x 415	50,000	21.0
BULK	198 x 84 x 20	1,000	459 x 214 x 256	50,000	19.5

Note: 1. Paper reel, white or gray color. Core material: plastic or metal.
 2. Components are packed in accordance with EIA standard RS-296-E.

ORDERING INFORMATION

Product No.	Package Type	Shipping Quantity
1N4933G-T3	DO-41	5000/Tape & Reel
1N4933G-TB	DO-41	5000/Tape & Box
1N4933G	DO-41	1000 Units/Box
1N4934G-T3	DO-41	5000/Tape & Reel
1N4934G-TB	DO-41	5000/Tape & Box
1N4934G	DO-41	1000 Units/Box
1N4935G-T3	DO-41	5000/Tape & Reel
1N4935G-TB	DO-41	5000/Tape & Box
1N4935G	DO-41	1000 Units/Box
1N4936G-T3	DO-41	5000/Tape & Reel
1N4936G-TB	DO-41	5000/Tape & Box
1N4936G	DO-41	1000 Units/Box
1N4937G-T3	DO-41	5000/Tape & Reel
1N4937G-TB	DO-41	5000/Tape & Box
1N4937G	DO-41	1000 Units/Box

1. Products listed in **bold** are WTE **Preferred** devices.
2. Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.
3. **To order RoHS / Lead Free version (with Lead Free finish), add "-LF" suffix to part number above. For example, 1N4933G-TB-LF.**

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WARNING: DO NOT USE IN LIFE SUPPORT EQUIPMENT. WTE power semiconductor products are not authorized for use as critical components in life support devices or systems without the express written approval.

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We power your everyday.